### Notification about the transfer of the semiconductor business

The semiconductor business of Panasonic Corporation was transferred on September 1, 2020 to Nuvoton Technology Corporation (hereinafter referred to as "Nuvoton"). Accordingly, Panasonic Semiconductor Solutions Co., Ltd. became under the umbrella of the Nuvoton Group, with the new name of Nuvoton Technology Corporation Japan (hereinafter referred to as "NTCJ").

In accordance with this transfer, semiconductor products will be handled as NTCJ-made products after September 1, 2020. However, such products will be continuously sold through Panasonic Corporation.

Publisher of this Document is NTCJ.

If you would find description "Panasonic" or "Panasonic semiconductor solutions", please replace it with NTCJ.

Except below description page
 "Request for your special attention and precautions in using the technical information and semiconductors described in this book"

Nuvoton Technology Corporation Japan

## **Panasonic**

MOS FET

### FC4B22690L

## FC4B22690L

# Gate resistor installed Dual N-channel MOS FET For lithium-ion secondary battery protection circuits

#### ■ Features

- Source-source On-state Resistance : RSS(on) typ. = 30 m $\Omega$  ( VGS = 4.0 V )
- CSP (Chip Size Package)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL : Level 1)
- Marking Symbol : 6K

#### Packaging

Embossed type (Thermo-compression sealing): 20 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

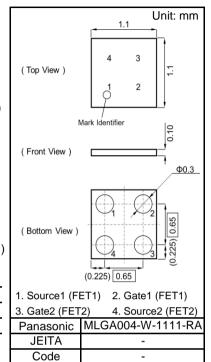
Absolute maximum ratings ra = 25 C								
Parameter		Symbol	Rating	Unit				
Source-source Voltage		VSS	20	V				
Gate-source Voltage	VGS	±12	V					
Source Current	DC	IS1 *1	3.4	A				
		IS2 <sup>*2</sup>	5.6					
		IS3 <sup>*3</sup>	7.3					
	Pulsed *4	ISp	34					
Total Power Dissipation	DC	PD1 *1	0.42	W				
		PD2 *2	1.1					
		PD3 <sup>*3</sup>	1.9					
Channel Temperature		Tch	150	°C				
Storage Temperature Range		Tsta	-55 to +150	°C				

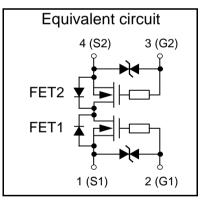
#### ■ Thermal Characteristics Ta = 25 °C

Parameter	Symbol	Rating	Unit	
	Rth1 *1	292	°C/W	
Thermal Resistance ( ch-a )	Rth2 *2	113		
	Rth3 *3	66		

Note \*1 Mounted on FR4 board (  $25.4~\text{mm} \times 25.4~\text{mm} \times t1.0~\text{mm}$  ). FR4 board partially covered with copper pad (  $18~\text{mm}^2$  area,  $36~\mu\text{m}$  thickness ).

- $^*2$  Mounted on FR4 board ( 25.4 mm  $\times$  25.4 mm  $\times$  t1.0 mm ). FR4 board fully covered with copper pad ( 608 mm² area, 36  $\mu m$  thickness ).
- \*3 Mounted on ceramic board ( 70 mm  $\times$  70 mm  $\times$  t1.0 mm ).
- \*4  $t = 10 \mu s$ , Duty Cycle  $\leq 1 \%$ .





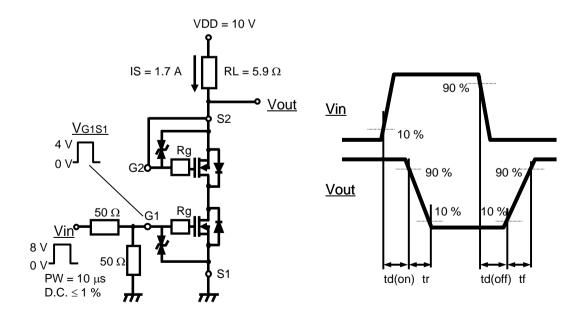
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#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Source-source Breakdown Voltage	VSSS	IS = 1 mA, VGS = 0 V	20			V	
Zero Gate Voltage Source Current	ISSS	VSS = 20 V, VGS = 0 V			1.0	μΑ	
Gate-source Leakage Current	IGSS1	$VGS = \pm 8 \text{ V}, VSS = 0 \text{ V}$			±1.0	μΑ	
	IGSS2	$VGS = \pm 3.8 \text{ V}, VSS = 0 \text{ V}$			±0.1		
Gate-source Threshold Voltage	Vth	IS = 0.16 mA, VSS = 10 V	0.35	0.9	1.4	V	
Source-source On-state Resistance	RSS(on)1	IS = 1.7 A, VGS = 4.5 V	23	28	32		
	RSS(on)2	IS = 1.7 A, VGS = 4.1 V	23.5	29.5	34		
	RSS(on)3	IS = 1.7 A, VGS = 4.0 V	24	30	35	mΩ	
	RSS(on)4	IS = 1.7 A, VGS = 3.8 V	24	30.5	36		
	RSS(on)5	IS = 1.7 A, VGS = 3.7 V	24.5	31	37		
	RSS(on)6	IS = 1.7 A, VGS = 3.1 V	25	33	40		
	RSS(on)7	IS = 1.7 A, VGS = 2.5 V	26	36	50		
Body Diode Forward Voltage	VF(s-s)	IF = 1.7 A, VGS = 0 V		8.0	1.2	V	
Input Capacitance *1	Ciss			426			
Output Capacitance *1	Coss	VSS = 10 V, VGS = 0 V, f = 1 kHz		84		pF	
Reverse Transfer Capacitance *1	Crss			71			
Turn-on Delay Time *1,*2	td(on)	VDD = 10 V, VGS = 0 to 4 V		0.11		μS	
Rise Time *1,*2	tr	IS = 1.7 A		0.28			
Turn-off Delay Time *1,*2	td(off)	VDD = 10 V, VGS = 4 to 0 V		0.66		μs	
Fall Time *1,*2	tf	IS = 1.7 A		0.46			
Total Gate Charge *1	Qg	VDD = 10 V		4.5			
Gate-source Charge *1	Qgs	VGS = 0 to 4 V		1.1		nC	
Gate-drain Charge *1	Qgd	IS = 3.4 A		1.2			

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

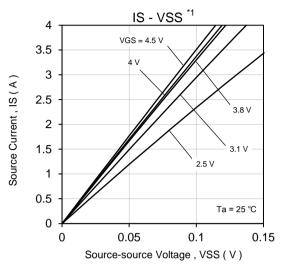
- \*1 Guaranteed by design, not subject to production testing.
- \*2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time.

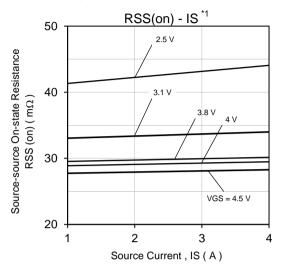


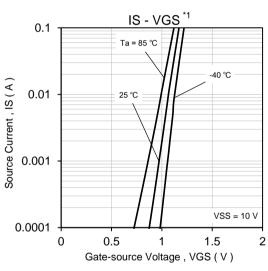
MOS FET

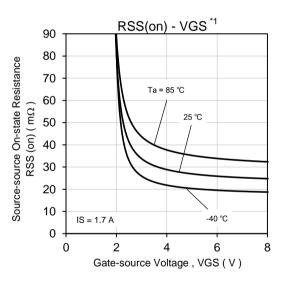
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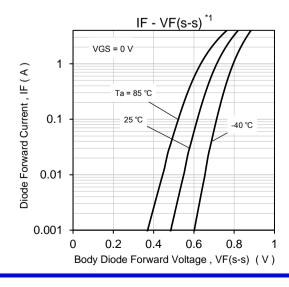
## Technical Data (reference)

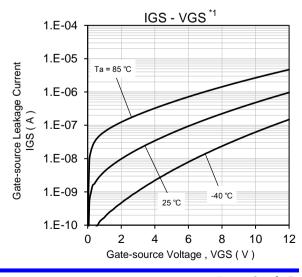












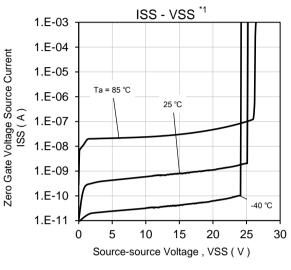
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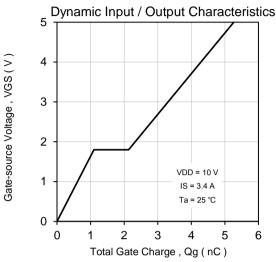
## **Panasonic**

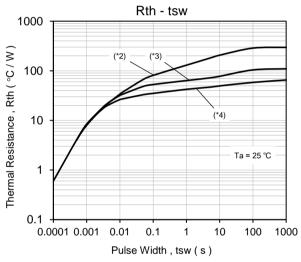
MOS FET

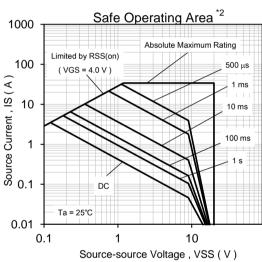
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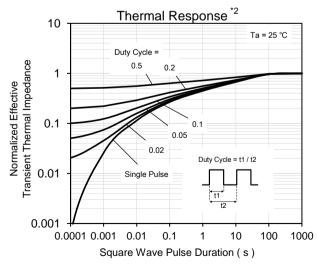
## Technical Data (reference)











#### Note

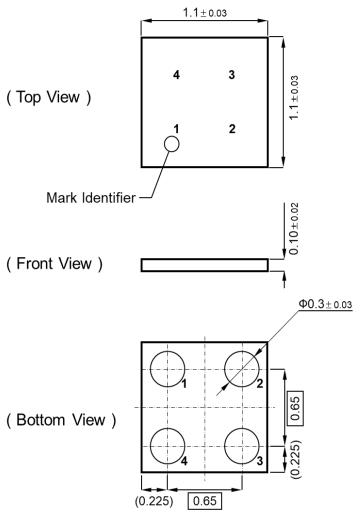
- \*1 Pulse measurement.
- \*2 Mounted on FR4 board (25.4 mm  $\times$  25.4 mm  $\times$  t1.0 mm). FR4 board partially covered with copper pad (18 mm<sup>2</sup> area, 36  $\mu$ m thickness).
- \*3 Mounted on FR4 board (  $25.4 \text{ mm} \times 25.4 \text{ mm} \times t1.0 \text{ mm}$  ). FR4 board fully covered with copper pad (  $608 \text{ mm}^2$  area,  $36 \mu \text{m}$  thickness ).
- \*4 Mounted on ceramic board ( 70 mm  $\times$  70 mm  $\times$  t1.0 mm ).

## **Panasonic**

MOS FET FC4B22690L

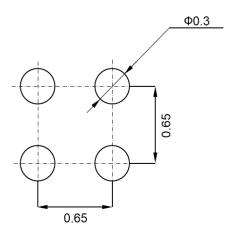
■ Outline

Unit: mm



■ Land & Stencil Pattern (reference)

Unit: mm



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